

## **Features**

- · Split Gate Trench MOSFET Technology
- Excellent Package for Heat Dissipation
- High Density Cell Design for Low R<sub>DS(on)</sub>
- Epoxy Meets UL 94 V-0 Flammability Rating
- · Moisture Sensitivity Level 1
- · Halogen Free Available Upon Request By Adding Suffix "-HF"
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

## **Maximum Ratings**

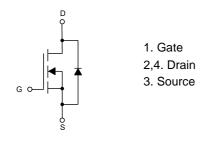
- Operating Junction Temperature Range : -55°C to +150°C
- Storage Temperature Range: -55°C to +150°C
- Thermal Resistance: 0.8°C/W Junction to Case

Parameter	Symbol	Rating	Unit	
Drain-Source Voltage		V <sub>DS</sub>	82	V
Gate-Source Volltage		V <sub>GS</sub>	±20	V
Continuous Drain Current	T <sub>C</sub> =25°C	1	100	Α
	T <sub>C</sub> =100°C	– I <sub>D</sub>	64	Α
Pulsed Drain Current (1)		I <sub>DM</sub>	400	Α
Avalanche Energy (2)		E <sub>AS</sub>	210	mJ
Total Power Dissipation		P <sub>D</sub>	156	W

#### Note:

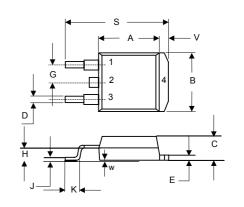
- 1. Pulse Test: Pulse Width≤300µs,Duty Cycle ≤2%.
- 2. T<sub>J</sub>=25°C, L=1.0mH, I<sub>AS</sub>=20.5A, V<sub>DD</sub>=50V.

### **Internal Structure**



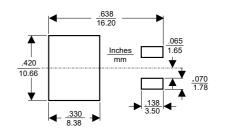
# N-CHANNEL MOSFET

# D2-PAK



DIMENSIONS					
DIM	INCHES		MM		NOTE
DIIVI	MIN	MAX	MIN	MAX	NOTE
Α	0.331	0.370	8.40	9.40	
В	0.378	0.417	9.60	10.60	
O	0.165	0.189	4.20	4.80	
D	0.027	0.037	0.68	0.94	
Е	0.045	0.055	1.14	1.40	
G	0.010		2.54		TYP.
Ι	0.096	0.134	2.43	3.40	
J	0.011	0.025	0.28	0.64	
K	0.071	0.131	1.80	3.32	
S	0.575	0.625	14.60	15.87	
V	0.042	0.058	1.07	1.47	
W	0.000	0.010	0.00	0.25	

#### Suggested Solder Pad Layout



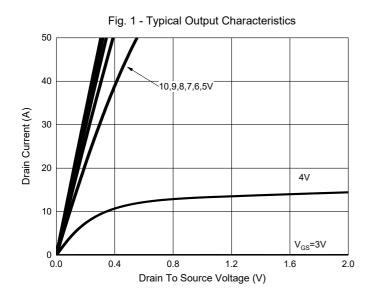


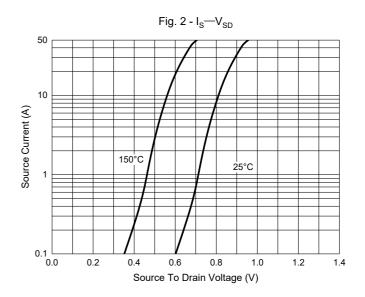
## Electrical Characteristics @ 25°C (Unless Otherwise Specified)

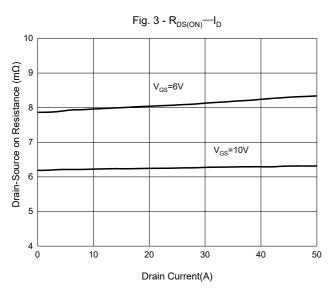
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Static Characteristics			1	1			
Drain-Source Breakdown Voltage	V <sub>(BR)DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =250μA	82			V	
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>DS</sub> =0V, V <sub>GS</sub> =±20V			±100	nA	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =64V, V <sub>GS</sub> =0V			1	μA	
Gate-Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS}=V_{GS}$ , $I_{D}=250\mu A$	1		3	V	
Drain-Source On-Resistance		V <sub>GS</sub> =10V, I <sub>D</sub> =20A		6.2	7.5	mΩ	
	R <sub>DS(on)</sub>	V <sub>GS</sub> =6V, I <sub>D</sub> =10A		8	10.5	mΩ	
Diode Characteristics			,				
Continuous Body Diode Current	Is				100	Α	
Diode Forward Voltage	V <sub>SD</sub>	V <sub>GS</sub> =0V, I <sub>S</sub> =20A			1.3	V	
Reverse Recovery Time	t <sub>rr</sub>	1 004 1/1/ 4004/		50		ns	
Reverse Recovery Charge	Q <sub>rr</sub>	I <sub>S</sub> =20A,di/dt=100A/µs		66		nC	
Dynamic Characteristics			,				
Input Capacitance	C <sub>iss</sub>			1826			
Output Capacitance	C <sub>oss</sub>	V <sub>DS</sub> =40V,V <sub>GS</sub> =0V,f=1MHz		337		pF	
Reverse Transfer Capacitance	C <sub>rss</sub>			30		1	
Total Gate Charge	$Q_g$			38			
Gate-Source Charge	Q <sub>gs</sub>	V <sub>DS</sub> =40V,V <sub>GS</sub> =10V,I <sub>D</sub> =20A		9.5		nC	
Gate-Drain Charge	$Q_{gd}$			10.3			
Turn-On Delay Time	t <sub>d(on)</sub>			13			
Turn-On Rise Time	t <sub>r</sub>	V <sub>DS</sub> =40V, V <sub>GEN</sub> =10V,		47		<b>F</b> -	
Turn-Off Delay Time	t <sub>d(off)</sub>	$R_G$ =4.5 $\Omega$ , $R_L$ =2 $\Omega$ , $I_{DS}$ =20A		32		ns	
Turn-Off Fall Time	t <sub>f</sub>			59			

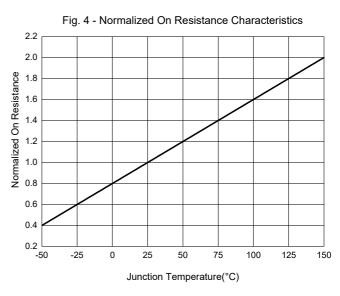


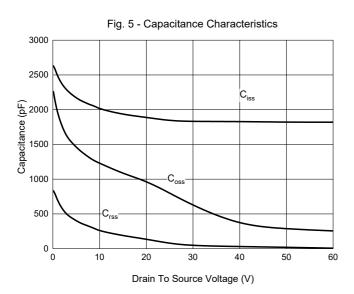
## **Curve Characteristics**

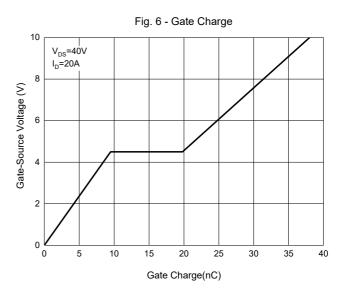






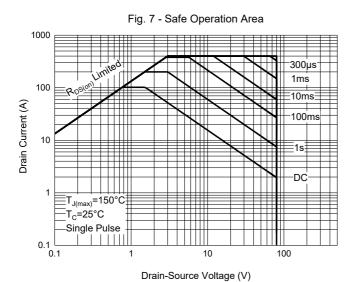








## **Curve Characteristics**





## **Ordering Information**

Device	Packing
Part Number-TP	Tape&Reel: 800pcs/Reel

Note : Adding "-HF" Suffix for Halogen Free, eg. Part Number-TP-HF

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